



IFW

PATENT
8040-1078

IN THE U.S. PATENT AND TRADEMARK OFFICE

In re application of

Tatsuo NAKAYAMA et al.

Conf. 2538

Application No. 10/590,730

Group 2818

Filed March 15, 2007

Examiner Ngan V Ngo

OHMIC ELECTRODE STRUCTURE OF NITRIDE SEMICONDUCTOR DEVICE

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

June 16, 2008

Sir:

Responsive to the Official Action of May 16, 2008,
please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing
of claims which begins on page 2 of this paper.

Remarks begin on page 6 of this paper.